

# MT29E1T208ECHBBJ4-3:B

## MT29E1T208ECHBBJ4-3:B Information

Heisener.com	 MT29E1T208ECHBBJ4-3:B Micron Technology Inc. Integrated Circuits (ICs) Memory IC FLASH 1.125T PARALLEL VBGA - For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

# **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



# MT29E1T208ECHBBJ4-3:B Specifications

Manufacturer Part Number	MT29E1T208ECHBBJ4-3:B
Manufacturer	Micron Technology Inc.
Category	Integrated Circuits (ICs)
	Memory
Package	-
Series	-
Memory Type	Non-Volatile
Memory Format	FLASH
Technology	FLASH - NAND
Memory Size	1.125Tb (144G x 8)
Memory Interface	Parallel
Clock Frequency	-
Write Cycle Time - Word, Page	-
Access Time	-
Voltage - Supply	2.5 V ~ 3.6 V
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	-
Package / Case	-
Supplier Device Package	-
	Report errors?

### MT29E1T208ECHBBJ4-3:B Guarantees



**Quality Guarantees** 

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

#### MT29E1T208ECHBBJ4-3:B Payment Methods



If you have any question about MT29E1T208ECHBBJ4-3:B, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com